Unit: mm

TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (π-MOSIII)

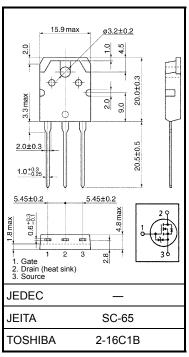
2SK2719

Chopper Regulator, DC-DC Converter and Motor Drive Applications

- Low drain-source ON resistance: $RDS(ON) = 3.7 \Omega$ (typ.)
- High forward transfer admittance: $|Y_{fs}| = 2.6 \text{ S}$ (typ.)
- Low leakage current: $I_{DSS} = 100 \ \mu A \ (max) \ (V_{DS} = 720 \ V)$
- Enhancement mode: $V_{th} = 2.0 \sim 4.0 \text{ V} (V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit	
Drain-source voltage		V _{DSS}	900	V	
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	900	V	
Gate-source voltage		V _{GSS}	±30	V	
Drain current	DC (Note 1)	Ι _D	3	A	
	Pulse (Note 1)	I _{DP}	9		
Drain power dissipation (Tc = 25° C)		PD	125	W	
Single pulse avalanche energy (Note 2)		E _{AS}	295	mJ	
Avalanche current		I _{AR}	3	А	
Repetitive avalanche energy (Note 3)		E _{AR}	12.5	mJ	
Channel temperature		T _{ch}	150	°C	
Storage temperature range		T _{stg}	-55~150	°C	



Weight: 4.6 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit	
Thermal resistance, channel to case	R _{th (ch-c)}	1.0	°C/W	
Thermal resistance, channel to ambient	R _{th (ch-a)}	50.0	°C/W	

Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: $V_{DD} = 25 \text{ V}, \text{ T}_{ch} = 25^{\circ}\text{C}$ (initial), L = 58 μ H, R_G = 25 Ω , I_{AR} = 45 A

Note 3: Repetitive rating: pulse width limited by maximum junction temperature

This transistor is an electrostatic-sensitive device. Please handle with caution.

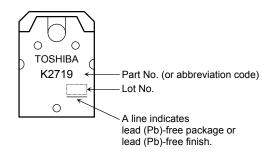
Electrical Characteristics (Ta = 25°C)

Chara	acteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 30$ V, $V_{DS} = 0$ V	_		±10	μΑ
Gate-source brea	akdown voltage	V (BR) GSS	$I_G=\pm 10~\mu A,~V_{DS}=0~V$	±30			V
Drain cut-off curre	ent	I _{DSS}	$V_{DS} = 720 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_		100	μΑ
Drain-source brea	akdown voltage	V (BR) DSS	$I_D = 10 \text{ mA}, V_{GS} = 0 \text{ V}$	900	_	_	V
Gate threshold vo	oltage	V _{th}	$V_{DS} = 10 \text{ V}, \text{ I}_{D} = 1 \text{ mA}$	2.0		4.0	V
Drain-source ON	resistance	R _{DS (ON)}	$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$	_	3.7	4.3	Ω
Forward transfer	admittance	Y _{fs}	$V_{DS} = 20 \text{ V}, \text{ I}_{D} = 1.5 \text{ A}$	0.65	2.6	_	S
Input capacitance	put capacitance C _{iss}			_	750	_	pF
Reverse transfer capacitance		C _{rss}	$V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$	_	10	_	pF
Output capacitance		Coss		_	70	_	pF
Switching time	Rise time	tr	V_{GS} V_{GS} V_{GS} V_{GS} V_{U}	_	15	_	- ns
	Turn-on time	t _{on}			55	_	
	Fall time	t _f		_	30		
	Turn-off time	t _{off}	Duty \leq 1%, t_{W} = 10 μs	_	110	_	
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \simeq 400$ V, V_{GS} = 10 V, I_D = 3 A	_	25	_	nC
Gate-source charge		Q _{gs}			13	_	nC
Gate-drain ("miller") charge		Q _{gd}]		12	_	nC

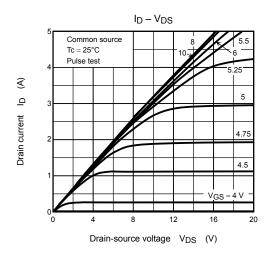
Source-Drain Diode Ratings and Characteristics (Ta = 25°C)

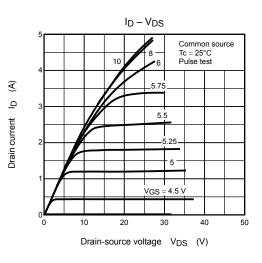
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	I _{DR}	_	_	_	3	A
Pulse drain reverse current (Note 1)	I _{DRP}	_	_		9	A
Diode forward voltage	VDSF	$I_{DR}=3~A,~V_{GS}=0~V$	_	_	-1.9	V
Reverse recovery time	t _{rr}	$I_{DR} = 3 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	_	1100	_	ns
Reverse recovery charge	Q _{rr}	$dI_{DR}/dt = 100 \text{ A}/\mu\text{s}$		7.5		μC

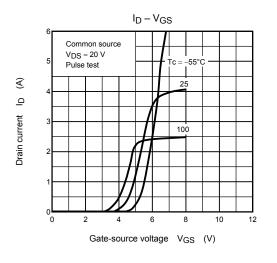
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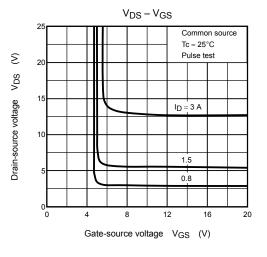


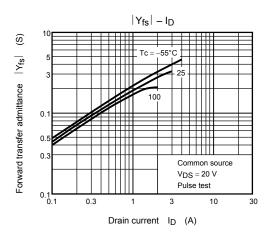
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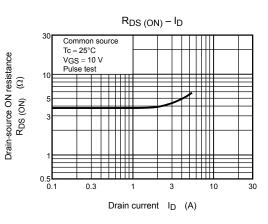




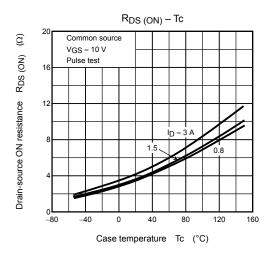


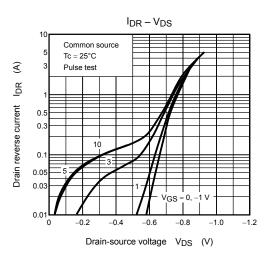


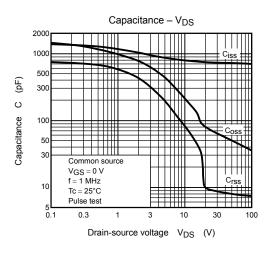


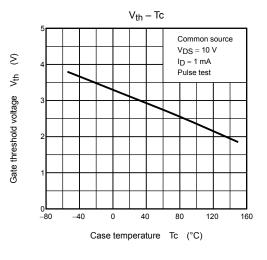


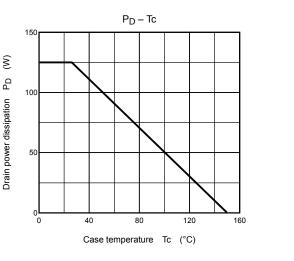
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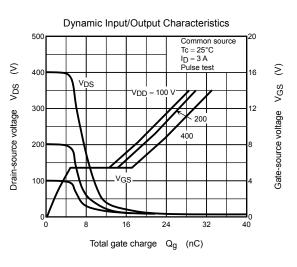




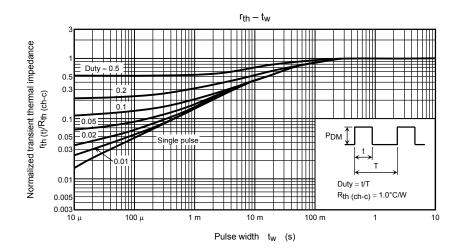


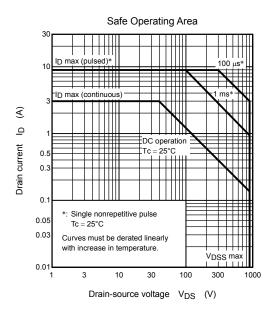


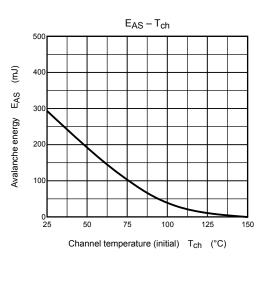


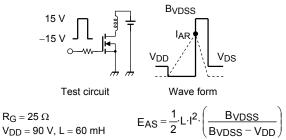


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